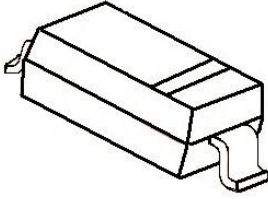


## SOD-123

## 500mW SOD-123 Fast Switching Diode



MARKING:



## 特征 Features

- 开关速度小于 4.0nS; Fast Switching Device (TRR <4.0 nS)
- 最大功率耗散 500mW; Power Dissipation of 500mW
- 高稳定性和可靠性。High Stability and High Reliability
- 反向漏电流小。Low reverse leakage

## 机械数据 Mechanical Data

- 封装: SOD-123 封装 SOD-123 Small Outline Plastic Package
- 极性: 色环端为负极 Polarity: Color band denotes cathode end
- 环氧树脂UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性(TA = 25℃ 除非另有规定)

**Maximum Ratings & Thermal Characteristics** (Ratings at 25℃ ambient temperature unless otherwise specified.)

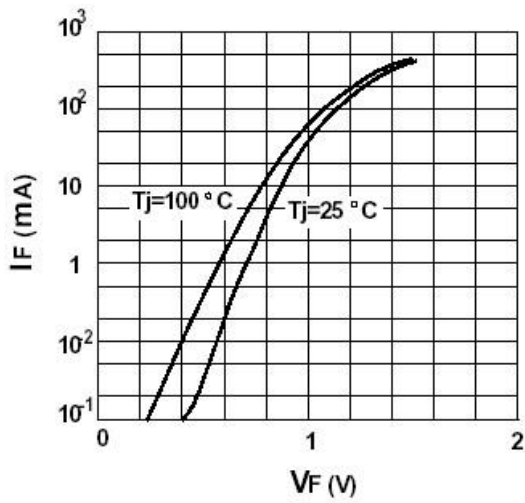
| 参数 Parameters                                             | 符号 Symbol        | 数值 Value | 单位 Unit |
|-----------------------------------------------------------|------------------|----------|---------|
| 反向峰值电压 Peak Reverse Voltage                               | V <sub>RM</sub>  | 100      | V       |
| 功率消耗 Power Dissipation                                    | P <sub>d</sub>   | 500      | mW      |
| 工作结温 Operating junction temperature                       | T <sub>j</sub>   | 150      | ℃       |
| 存储温度 Storage temperature range                            | T <sub>STG</sub> | -65-+150 | ℃       |
| 热阻 Thermal Resistance from Junction to Ambient            | R <sub>θJA</sub> | 250      | ℃/W     |
| 平均整流电流 Average Rectified Current                          | I <sub>O</sub>   | 150      | mA      |
| 正向(不重复)电流 Non-repetitive Peak Forward Current             | I <sub>FM</sub>  | 300      | mA      |
| 正向(不重复)浪涌电流 Peak Forward Surge Current<br>@tp=1us; TA=25℃ | I <sub>FSM</sub> | 2.0      | A       |

Valid provided that electrodes are kept at ambient temperature.

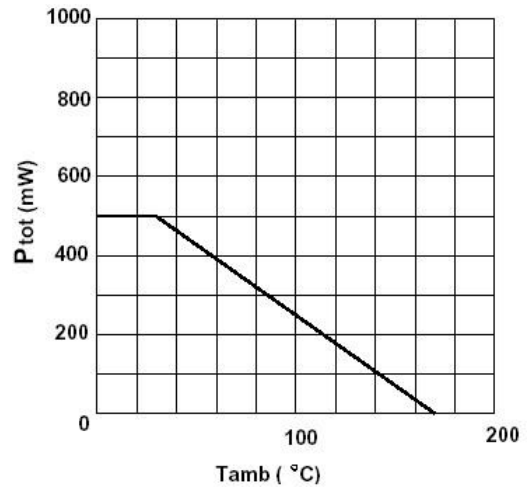
电特性 **Electrical Characteristics** (Ratings at 25℃ ambient temperature unless otherwise specified).

| 符号<br>Symbols  | 参数<br>Parameter                  | 测试条件<br>Test Condition                                                          | 界限 Limits |      | 单位<br>Unit |
|----------------|----------------------------------|---------------------------------------------------------------------------------|-----------|------|------------|
|                |                                  |                                                                                 | Min       | Max  |            |
| BV             | 反向击穿电压<br>Breakdown Voltage      | I <sub>R</sub> =100uA                                                           | 100       |      | V          |
| I <sub>R</sub> | 反向漏电流<br>Reverse Leakage Current | V <sub>R</sub> =20V                                                             | ---       | 25   | nA         |
|                |                                  | V <sub>R</sub> =20V T <sub>j</sub> =150℃                                        | ---       | 50   | uA         |
|                |                                  | V <sub>R</sub> =75                                                              | ---       | 5    | uA         |
| V <sub>F</sub> | 正向电压<br>Forward Voltage          | I <sub>F</sub> =10mA                                                            | ---       | 1.00 | V          |
|                |                                  | I <sub>F</sub> =100mA                                                           | ---       | 1.25 |            |
| TRR            | 反向恢复时间<br>Reverse Recovery Time  | I <sub>F</sub> = I <sub>R</sub> = 10mA,<br>I <sub>rr</sub> =0.1X I <sub>R</sub> | ---       | 4    | nS         |
|                |                                  | RL=100Ω                                                                         |           |      |            |
|                |                                  |                                                                                 |           |      |            |
| C              | 结电容<br>Capacitance               | V <sub>R</sub> =0V, f=1MHZ                                                      | ---       | 4    | pF         |

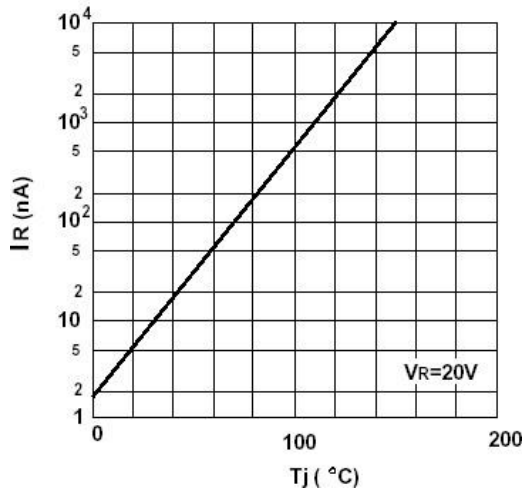
Forward characteristics



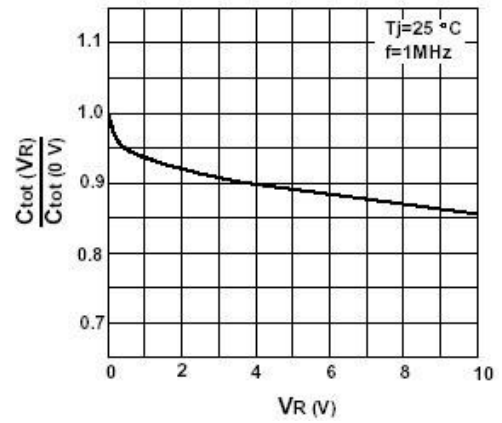
Admissible power dissipation versus ambient temperature



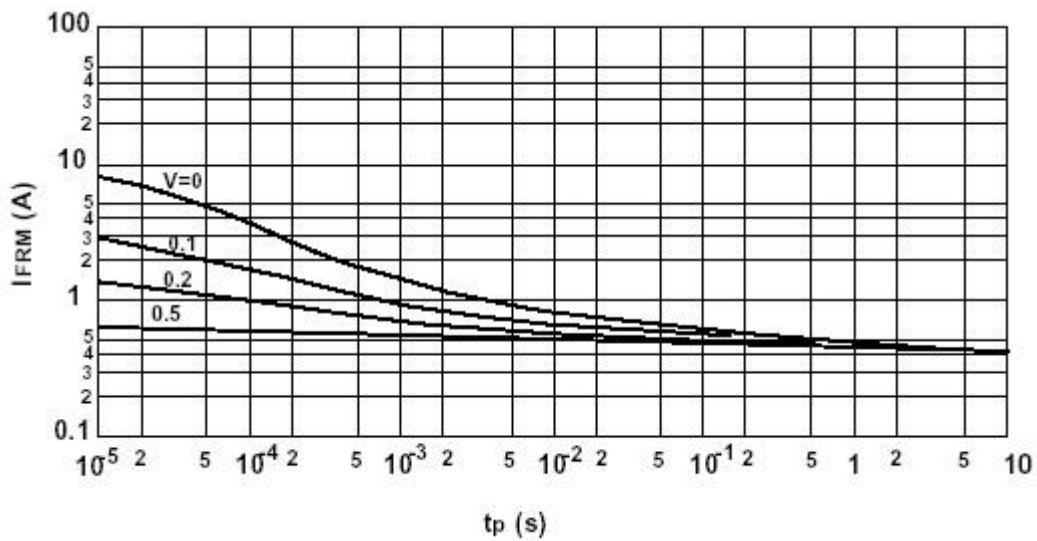
Leakage current versus junction temperature



Reverse capacitance VS. reverse voltage

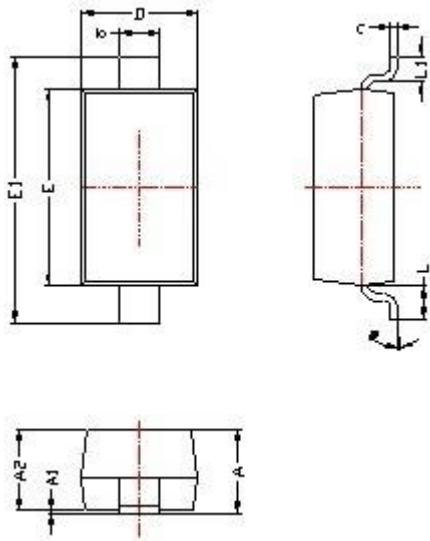


Admissible repetitive peak forward current VS. pulse duration



SOD-123 PACKAGE OUTLINE

Plastic surface mounted package

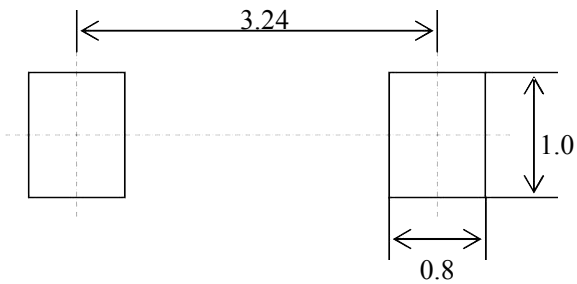


| SYMBOL | DIMENSIONS |       |
|--------|------------|-------|
|        | MIN.       | MAX.  |
| A      | 1.050      | 1.250 |
| A1     | 0.000      | 0.100 |
| A2     | 1.050      | 1.150 |
| b      | 0.450      | 0.650 |
| c      | 0.080      | 0.150 |
| D      | 1.500      | 1.700 |
| E      | 2.600      | 2.800 |
| E1     | 3.550      | 3.850 |
| L      | 0.500REF   |       |
| L1     | 0.250      | 0.450 |
| theta  | 0°         | 8°    |

焊盘设计参考

Precautions: PCB Design

Recommended land dimensions for SOD-123 diode. Electrode patterns for PCBs



中心距: 3.24  
脚宽: 0.55  
焊盘宽: 1.00  
脚长: 0.50  
焊盘长: 0.80

技术要求:

- 1, 塑封体尺寸: 2.70 X 1.60
- 2: 未注公差为: ±0.05
- 3, 所有单位: mm